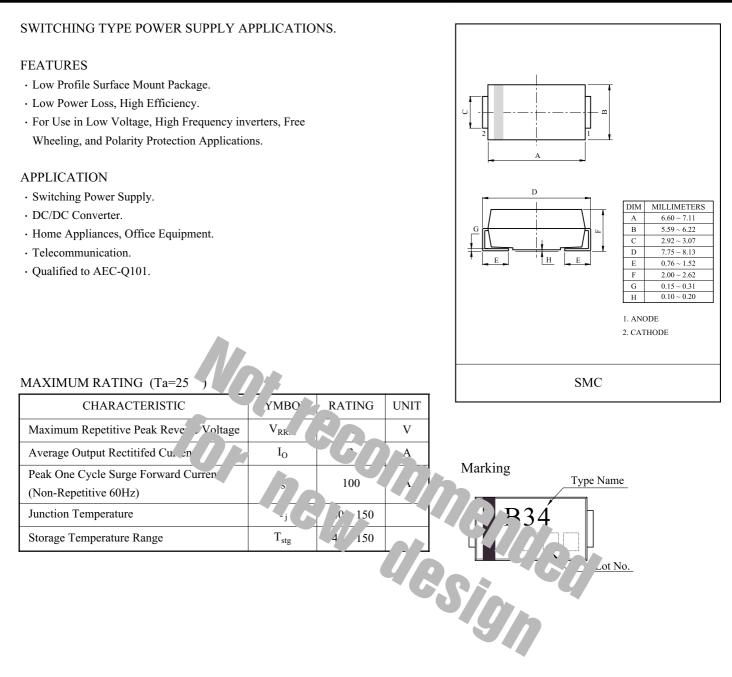


## SEMICONDUCTOR TECHNICAL DATA

# SMCB34

### SCHOTTKY BARRIER TYPE DIODE



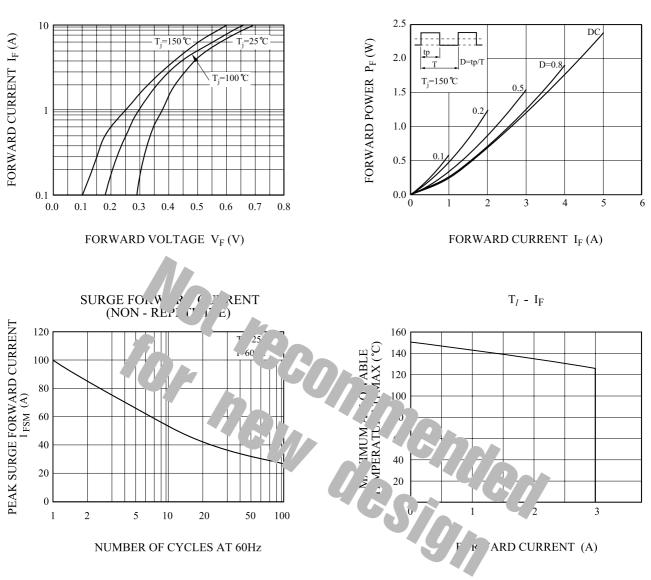
#### ELECTRICAL CHARACTERISTICS (Ta=25 )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V <sub>FM</sub>	I <sub>FM</sub> =3A	-	-	0.5	V
Repetitive Peak Reverse Current	I <sub>RRM</sub>	V <sub>RRM</sub> =Rated, Tj=25	-	-	0.1	mA
		V <sub>RRM</sub> =Rated, Tj=100	-	-	10	mA
Total Capacitance	CT	V <sub>R</sub> =4V, f=1MHz	-	-	250	pF
Thermal Resistance	R <sub>th(j-1)</sub>	Junction to lead	-	-	10	/W
	R <sub>th(j-a)</sub>	Junction to ambient	-	-	50	/W

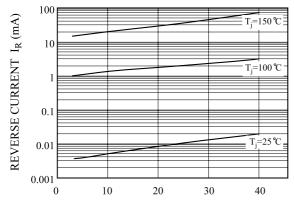
## SMCB34

 $P_F$  -  $I_F$ 

 $I_F$  -  $V_F$ 







REVERSE VOLTAGE  $V_R(V)$